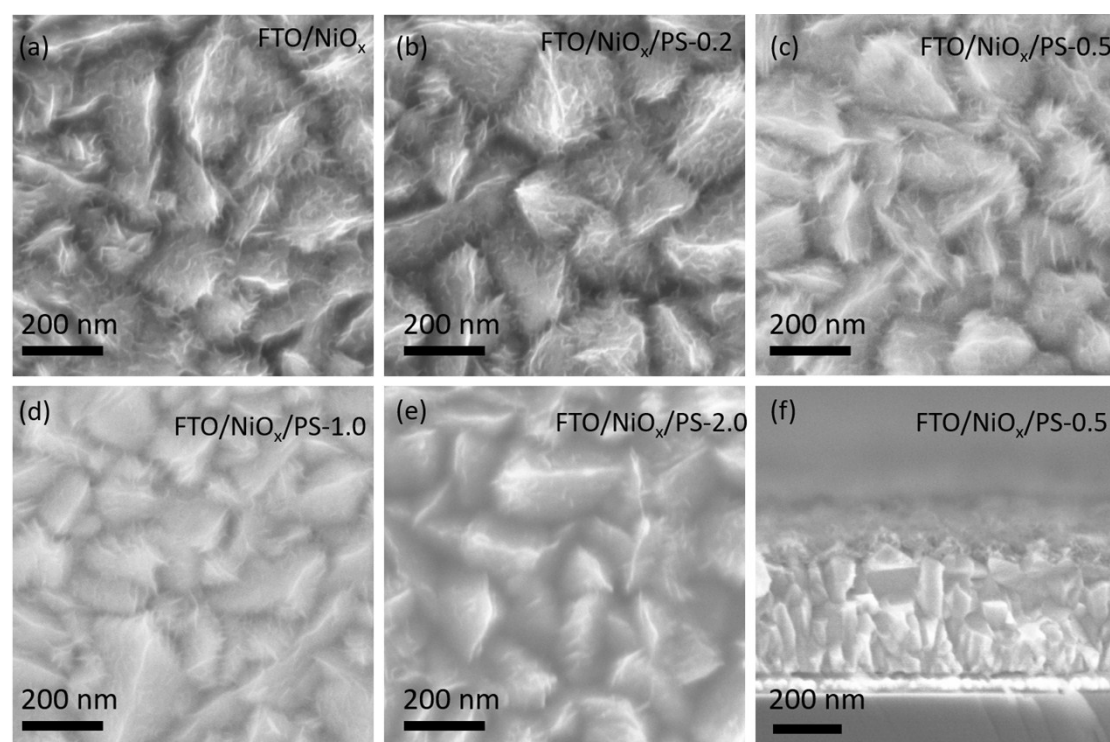


## Supporting Information

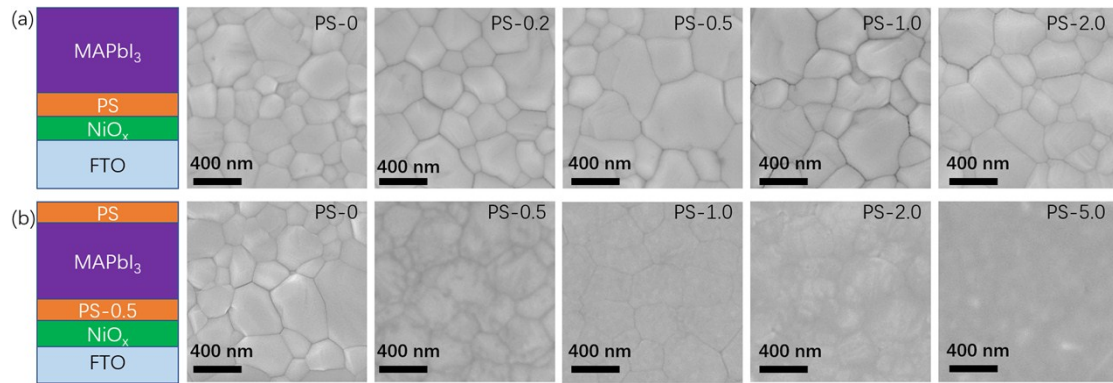
# Highly efficient and stable perovskite solar cells via bilateral passivation layers

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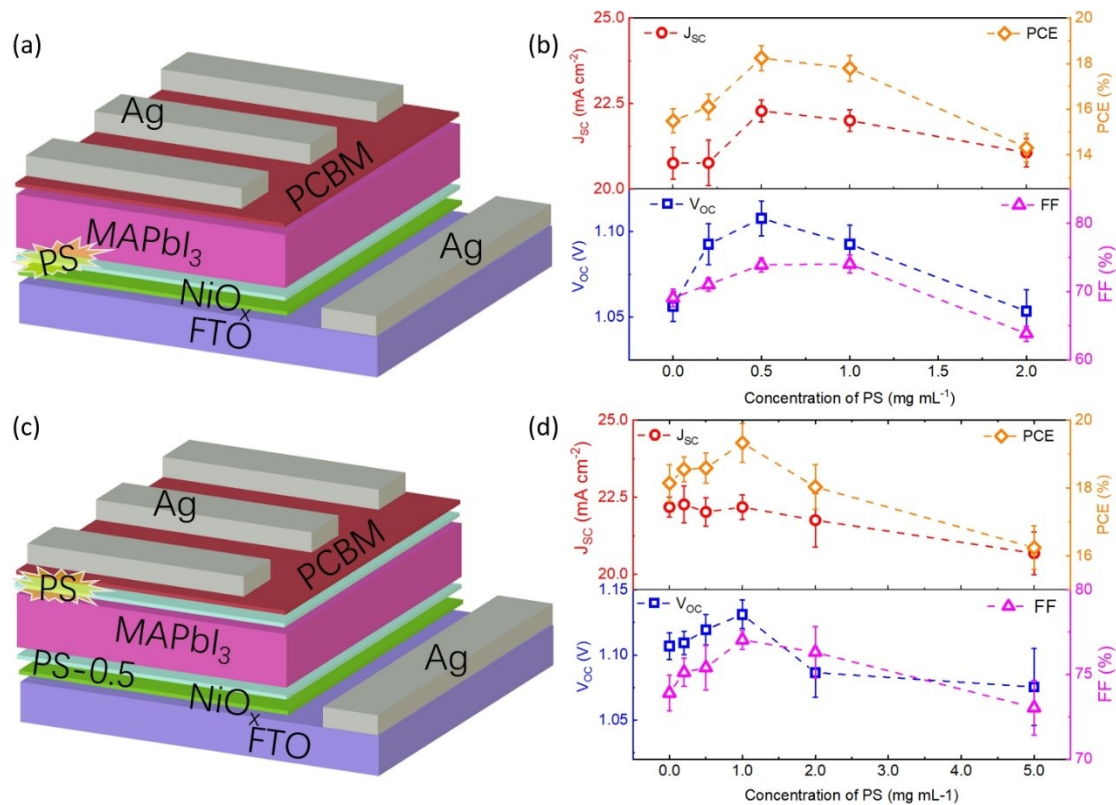
**Figure S1.** Top-view SEM images of FTO/NiO<sub>x</sub> sample deposited with different PS concentrations (mg mL<sup>-1</sup>) at (a) 0, (b) 0.2, (c) 0.5, (d) 1.0 and (e) 2.0. (f) The cross-sectional SEM image of the FTO/NiO<sub>x</sub> sample deposited with PS at the concentration of 0.5 mg mL<sup>-1</sup>. The numbers in the images represent the PS concentration (mg mL<sup>-1</sup>) dissolved in chlorobenzene.



**Figure S2.** Structure diagrams of three different structures, (a) FTO/NiO<sub>x</sub>/PS/MAPbI<sub>3</sub> and (b) FTO/NiO<sub>x</sub>/PS-0.5/MAPbI<sub>3</sub>/PS and the corresponding top-view SEM images. (a) Perovskite films depositing on the bottom passivation layer with different PS concentrations from 0 to 2.0 mg mL<sup>-1</sup>. (b) Perovskite films depositing on the bottom passivation film (PS-0.5) with different PS concentration from 0 to 5.0 mg mL<sup>-1</sup>, here the PS/CB solution acts as the antisolvent.

**Table S1.** Photovoltaic parameters of the PSCs based on bottom passivation layer at various concentrations of PS solution.

$C_{PS}$ (mg mL <sup>-1</sup> )	$V_{OC}$ (V)	$J_{SC}$ (mA cm <sup>-2</sup> )	FF (%)	PCE (%)
0	1.050	21.11	71.74	15.90
0.2	1.099	21.12	72.85	16.91
0.5	1.108	22.45	73.94	18.39
1.0	1.092	22.10	74.36	17.95
2.0	1.062	21.22	64.31	14.49



**Figure S3.** Three-dimensional schematic diagram of the PSC with (a) a bottom passivation layer and (c) bilateral passivation layers. Statistics of  $V_{OC}$ ,  $J_{SC}$ , FF and PCE for (b) bottom and (d) bilaterally passivated PSCs with different PS concentrations.

**Table S2.** Photovoltaic parameters of the bilaterally passivated PSCs based on bottom passivation of PS-0.5 and various concentrations for preparing top passivation layer.

$C_{PS}$ (mg mL <sup>-1</sup> )	$V_{OC}$ (V)	$J_{SC}$ (mA cm <sup>-2</sup> )	FF (%)	PCE (%)
0	1.108	22.45	73.94	18.39
0.5	1.129	22.51	75.44	19.17
1.0	1.149	22.51	77.33	19.99
2.0	1.104	21.62	78.22	18.67
5.0	1.094	21.09	74.41	17.16

Table S3. Summarization of the open-circuit voltage for various perovskite solar cells.

Device structure	PCE (%)	$V_{OC}$ (V)	Year/Ref.
ITO/NiO <sub>x</sub> /MAPbI <sub>3</sub> /C <sub>60</sub> /BCP/Ag	18.18	1.09	2018 <sup>1</sup>
ITO/NiO <sub>x</sub> :rGO/MAPbI <sub>3</sub> /PCBM/BCP/Ag	18.90	1.07	2019 <sup>2</sup>
FTO/PEDOT:PSS/MAPbI <sub>3</sub> /HBM/Ag	20.60	1.12	2019 <sup>3</sup>
FTO/TiO <sub>2</sub> /MAPbI <sub>3</sub> /Spiro-OMeTAD/Au	18.70	1.10	2019 <sup>4</sup>
ITO/P3CT-N/MAPbI <sub>3</sub> /IT-4X/s-Bphen/Ag	17.65	1.08	2019 <sup>5</sup>
FTO/Zn:NiO <sub>x</sub> /MAPbI <sub>3</sub> /PCBM/BCP/Ag	18.98	1.08	2019 <sup>6</sup>
ITO/PTAA/MAPbI <sub>3</sub> /C <sub>60</sub> /BCP/Ag	19.50	1.09	2019 <sup>7</sup>
ITO/SnO <sub>2</sub> /MAPbI <sub>3</sub> /Spiro-OMeTAD/P3HT/Au	18.50	1.10	2019 <sup>8</sup>
FTO/TiO <sub>2</sub> NW/MAPbI <sub>3</sub> /Spiro-OMeTAD/Au	19.50	1.12	2019 <sup>9</sup>
FTO/TiO <sub>2</sub> MCP/MAPbI <sub>3</sub> /Spiro-OMeTAD/Au	20.08	1.09	2019 <sup>10</sup>
FTO/TiO <sub>2</sub> /MAPbI <sub>3</sub> /Spiro-OMeTAD/Au	18.59	1.11	2019 <sup>11</sup>
FTO/NiO <sub>x</sub> /PS/MAPbI <sub>3</sub> /PS/PCBM/Ag	19.99	1.149	Our work

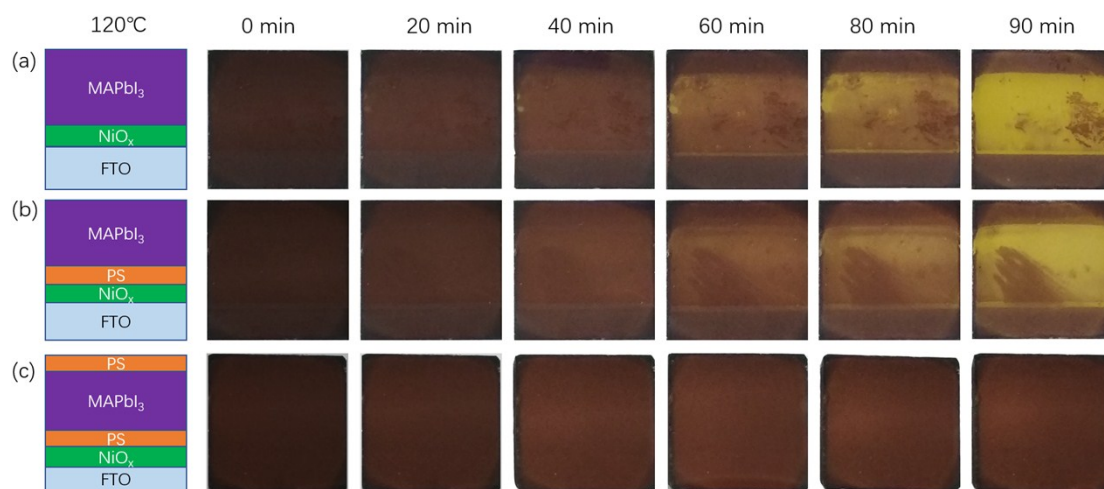


Figure S4. Photographs of (a) the pristine perovskite film without passivation layers

and (b) bottom and (c) bilateral-passivated perovskite films annealed at 120 °C in ambient air (humidity 60%) for different times.

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